

## DIELECTRONIC RECOMBINATION IN THE GASEOUS NEBULAE AS A COOLING PROCESS

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The dielectronic recombination (DR) is of importance at 'low' (nebular) temperature [1]. This process leads to cooling the electron gas in nebulae. The cooling rate by recombination of ion  $X^{+n}$  is

$$L_{dr}(T_e) = \sum_j \frac{4 \pi^{3/2} a_0^3}{(k T_e / Ry)^{3/2}} \frac{g_j W_j^a}{g^+} \exp\left(-\frac{\Delta E_j}{k T_e}\right) \frac{W_j^r}{W_j^a + W_j^r} \Delta E_j.$$

Here  $W_j^r$  and  $W_j^a$  are respectively the radiation and autoionization probabilities for the autoionization state  $j$  of ion  $X^{+n}$ ,  $\Delta E_j$  is the energy of this state,  $g_j$  and  $g^+$  are respectively the statistical weights of the state  $j$  and the ground state of the ion  $X^{+n+1}$ . We have calculated  $L_{dr}(T_e)$  for all ions of C. It is shown that the process of DR cooling is important only for nebulae with extraordinarily high abundances ( $\{C^{+i}/H^+\} > 0.01$ ) of these ions.

### References

- [1]. Nussbaumer H., Storey P.J. (1984) 'Dielectronic recombination at low temperature. II: Recombination coefficients for lines at C, N, O', *Astronomy and Astrophysics*, **56**, 293-312.